

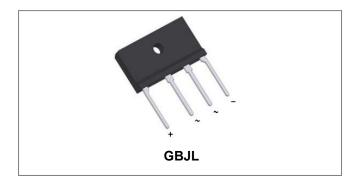
GBJL25J THRU GBJL25M

Technical Data Data Sheet N2254, Rev. -

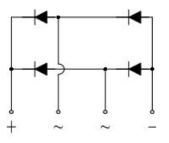


# GBJL25J-GBJL25M

# Single-Phase 15.0A Glass Passivated Bridge Rectifier



# **Circuit Diagram**



### Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# Mechanical Data

- Case: GBJL, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on body
- Mounting Position: Any
- Lead Free: For RoHS / Lead Free Version
- Mounting Torgue: 10cm-kg (8.8inches-lbs) max;
- Recommend Torgue:Mounting Torgue: 5.7cm-kg (5inches-lbs);

### Maximum Ratings @T<sub>A</sub>=25°C unless otherwise specified

Type Number	Symbol	GBJL25J	GBJL25K	GBJL25M	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>DC</sub>	600	800	1000	v
RMS Reverse Voltage	V <sub>RMS</sub>	420	560	700	V
Average forward rectified output current @Tc =110°C	I <sub>(AV)</sub>	25.0		A	
Peak Forward Surge Current,8.3ms single half- sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>	350		A	
Rating for fusing (t<8.3ms)	l²t	508		A <sup>2</sup> sec	

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### GBJL25J THRU GBJL25M

RoHS 🧭

### Electrical Characteristics@T<sub>A</sub>=25°C unless otherwise specified

Type Number	Symbol	GBJL25J	GBJL25K	GBJL25M	Units
Forward Voltage (per element) @I <sub>F</sub> =12.5A	V <sub>F</sub>		1.0		V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	I <sub>RM</sub>		5 150		μA

\* Pulse width < 300  $\mu$ s, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

Type Number	Symbol	GBJL25J	GBJL25K	GBJL25M	Units
Typical Thermal Resistance (per leg)	R <sub>eja</sub> R <sub>ejl</sub>	22 <sup>(2)</sup> 2.5 <sup>(1)</sup>		°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150		°C	

Notes: 1. Unit case mounted on AI plate heatsink;

2. Units mounted on PCB without heatsink;

3. Recommended mounting position is to bolt down on heatsink with silicone thermal compound for maximum heat transfer with #6 screw.

# **Ratings and Characteristics Curves**

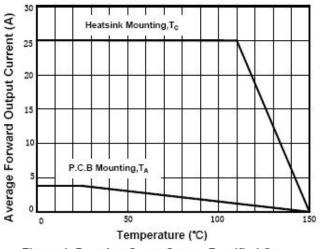
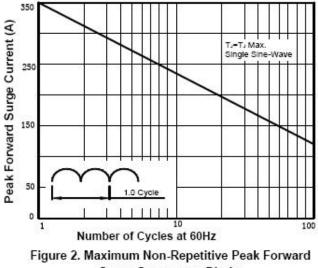


Figure 1. Derating Curve Output Rectified Current





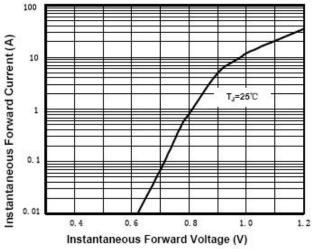
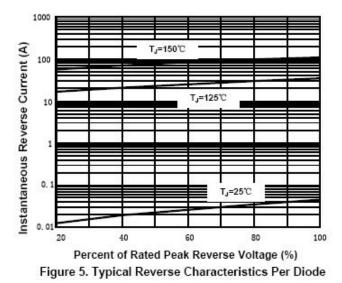


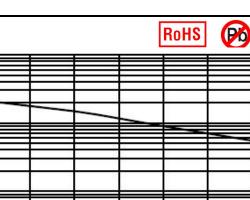
Figure 3. Typical Forward Characteristics Per Diode



**Ordering Information** 

Device	Package	Plating	Shipping
GBJL25J THRU GBJL25M	GBJL(Pb-Free)	Pure Sn	15pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.



10

100

1000

100

10

0.1

Junction Capacitance (pF)

# THRU GBJL25M

GBJL25J

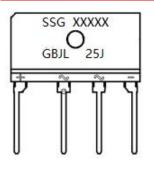


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Reverse Voltage (V)

Figure 4. Typical Junction Capacitance Per Diode

# **Marking Diagram**



Where XXXXX is YYWWL

SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number
GBJL25J	= Type Number

Cautions: Molding resin Epoxy resin UL:94V-0

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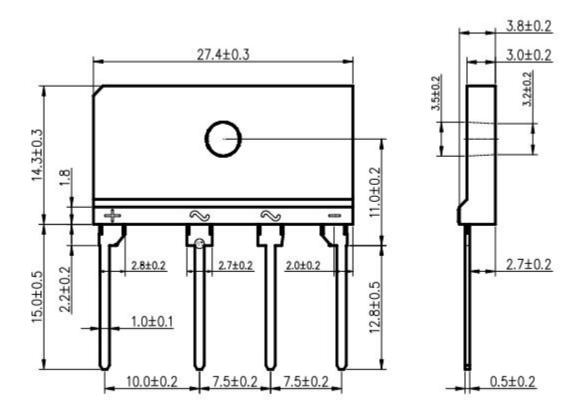


RoHS PO

GBJL25M

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# Mechanical Dimensions GBJL (Millimeters)



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